

Taiwan Semiconductor

200mA, 120V - 250V Switching Diodes

FEATURES

- Fast Switching Speed
- Surface Mount Package Ideally Suited For Automatic Insertion
- High Conductance
- Packing code with suffix "G" means green compound (halogen-free)
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

APPLICATION

Surface mount fast switching diode General purpose small signal switching

MECHANICAL DATA

- Case: SOD-323 small outline plastic package
- Moisture sensitivity level 1
- Polarity: Indicated by cathode band
- Weight: 4.36 ± 0.5 mg



SOD-323







MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS (T _A =25°C unless otherwise noted)						
PAR	AMETER	SYMBOL	BAV19WS-G	BAV20WS-G	BAV21WS-G	UNIT
Average Rectified Output Current		I _O	200		mA	
Repetitive Peak Reverse Voltage		V _{RRM}	120	200	250	V
DC Reverse Voltage		V _R	100	150	200	V
Non-Repetitive Peak Forward	Pulse Width = 1 µs	1	2.5 0.5		А	
Surge Current	Pulse Width = 1 s	IFSM				
Repetitive Peak Forward Surge Current		I _{FRM}		625		mA
Power Dissipation		PD	200		mW	
Thermal Resistance Junction to Ambient		R _{eja}	625		°C/W	
Junction and Storage Temperature Range		T _J , T _{STG}		-65 to 150		°C

PARAMETER		SYMBOL	MIN	MAX	UNIT
	BAV19WS-G		120	-	
Breakdown Voltage (Note 1)	BAV20WS-G	V _{(BR)R}	200	-	V
	BAV21WS-G		250	-	
	I _F =100mA	V	-	1.00	V
Forward Voltage	I _F =200mA	V _F	-	1.25	
	BAV19WS-G		-	100	nA
Reverse Leakage Current (Note 2)	BAV20WS-G	I _R			
	BAV21WS-G				
Junction Capacitance	V _R =0, f=1.0MHz	CJ	-	5	pF
Reverse Recovery Time (Note 3)		t _{rr}	-	50	ns

Note 1: Test condition : I_R = 100µA

Note 2: Test condition : BAV19WS-G @ V_R=100V, BAV20WS-G @ V_R=150V, BAV21WS-G @ V_R=200V

Note 3: Test condition : $~I_{F}\text{=}~I_{R}\text{=}~30\text{mA}$, $R_{L}\text{=}100\Omega$, $Irr\text{=}0.1\text{x}I_{R}$



Small Signal Product

RATINGS AND CHARACTERISTICS CURVES

(T_A=25°C unless otherwise noted)

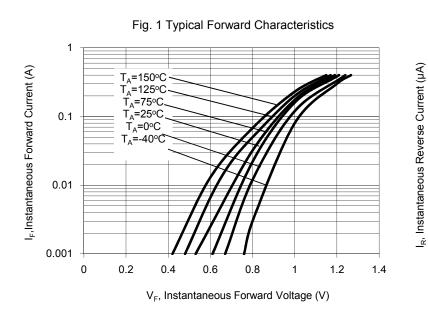


Fig. 3 Typical Capacitance VS. Reverse Voltage

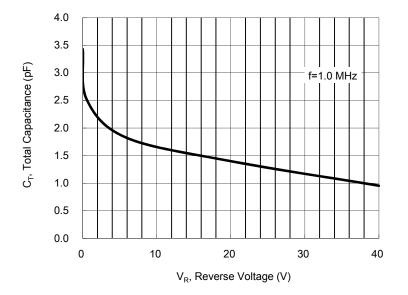


Fig. 4 Power Derating Curve

 $\rm V_{\rm R},$ Instantaneous Reverse Voltage (V)

150

Fig. 2 Typical Reverse Characteristics

T_A=125°C

T_A=75°C

T_A=25°C

T_A=0°C

T_A=-40°C

100

T_A=150°C

200

250

100

10

1

0.1

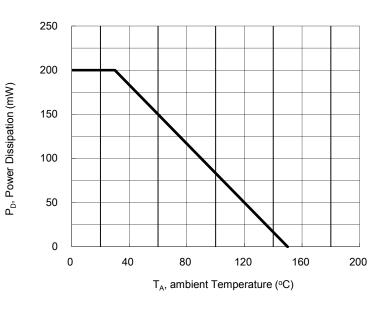
0.01

0.001

0.0001

0

50





BAV19WS-G/BAV20WS-G/BAV21WS-G Taiwan Semiconductor

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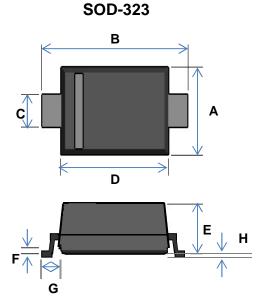
ORDERING INFO	ORMATION			
PART NO.	PACKING CODE	PACKING CODE SUFFIX	PACKAGE	PACKING
BAVxxWS-G (Note 1, 2)	RR	G	SOD-323	3K / 7" Reel

Note 1: "xx" is Device Code from "BAV19WS-G" to "BAV21WS-G".

Note 2: Whole series with green compound

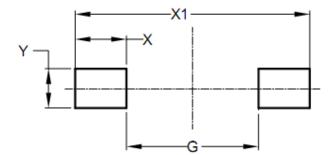
EXAMPLE				
PREFERRED P/N	PART NO.	PACKING CODE	PACKING CODE SUFFIX	DESCRIPTION
BAV19WS-G RRG	BAV19WS-G	RR	G	Green compound

DIMENSIONS



DIM.	Unit (mm)		Unit (inch)		
	Min Max		Min	Max	
А	1.150	1.400	0.045	0.055	
В	2.300	2.700	0.091	0.106	
С	0.250	0.450	0.010	0.018	
D	1.600	1.800	0.063	0.071	
Е	0.800	1.000	0.031	0.039	
F	0.050	0.177	0.002	0.007	
G	0.475 REF		0.019 REF		
Н	-	0.100	-	0.004	

SUGGESTED PAD LAYOUT



DIM.	Unit (mm)	Unit (inch)
	Тур.	Тур.
G	1.600	0.063
Х	0.630	0.025
X1	2.850	0.112
Y	0.830	0.033

Note: The suggested land pattern dimensions have been provided for reference only, as actual pad layouts may vary depending on application

MARKING

Part No.	Marking
BAV19WS-G	A8
BAV20WS-G	T2
BAV21WS-G	Т3

Document Number: DS_S0000021



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